

# Microwave studies of Wigner solid phases in bilayer systems

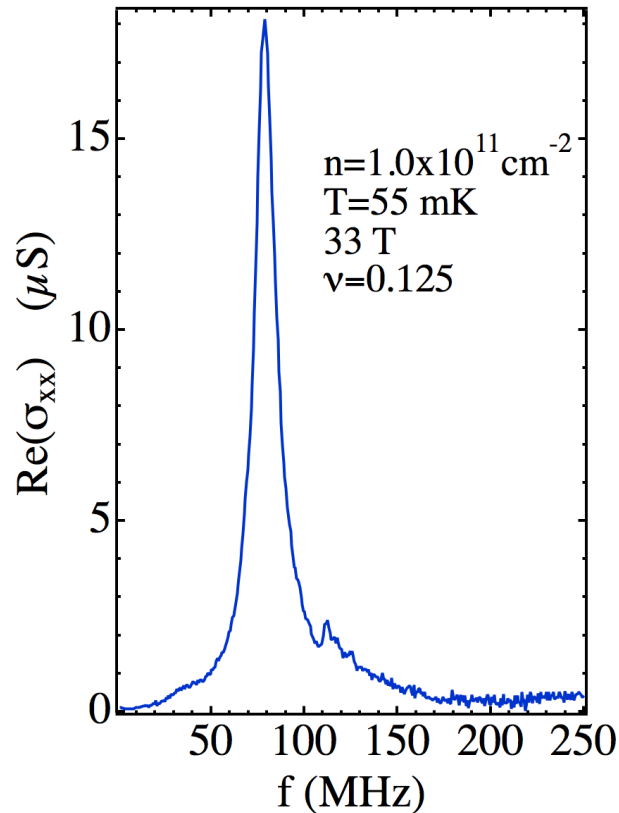
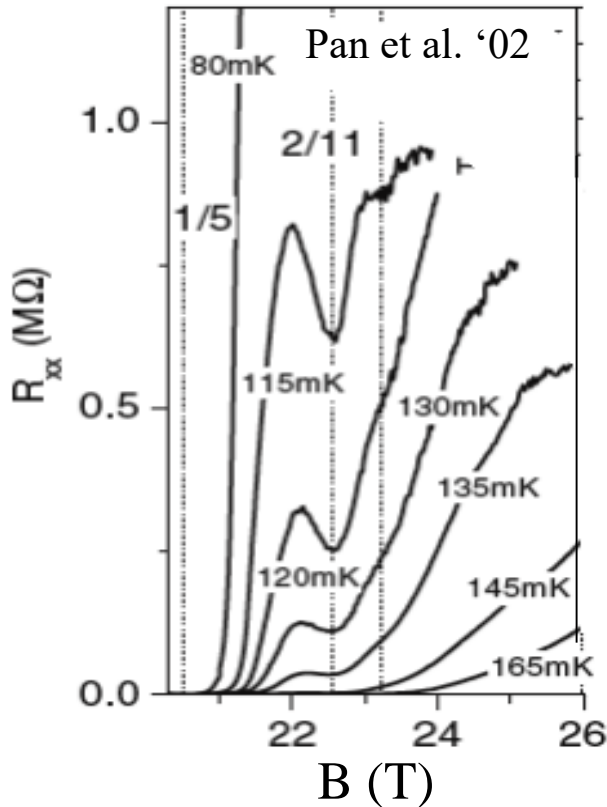
L. W. Engel, NHMFL/FSU

A. T. Hatke, NHMFL/FSU

Y. Liu, M. Shayegan, L. N. Pfeiffer,  
K. W. West and K. W. Baldwin, Princeton

# High B Termination of FQH series: insulator and resonance

3.



- experiment: insulation + resonance  $\nu \sim 1/5$
- Resonance: signature of pinned Wigner crystal
- resonance understood as **pinning mode**, in which solid oscillates within disorder potential

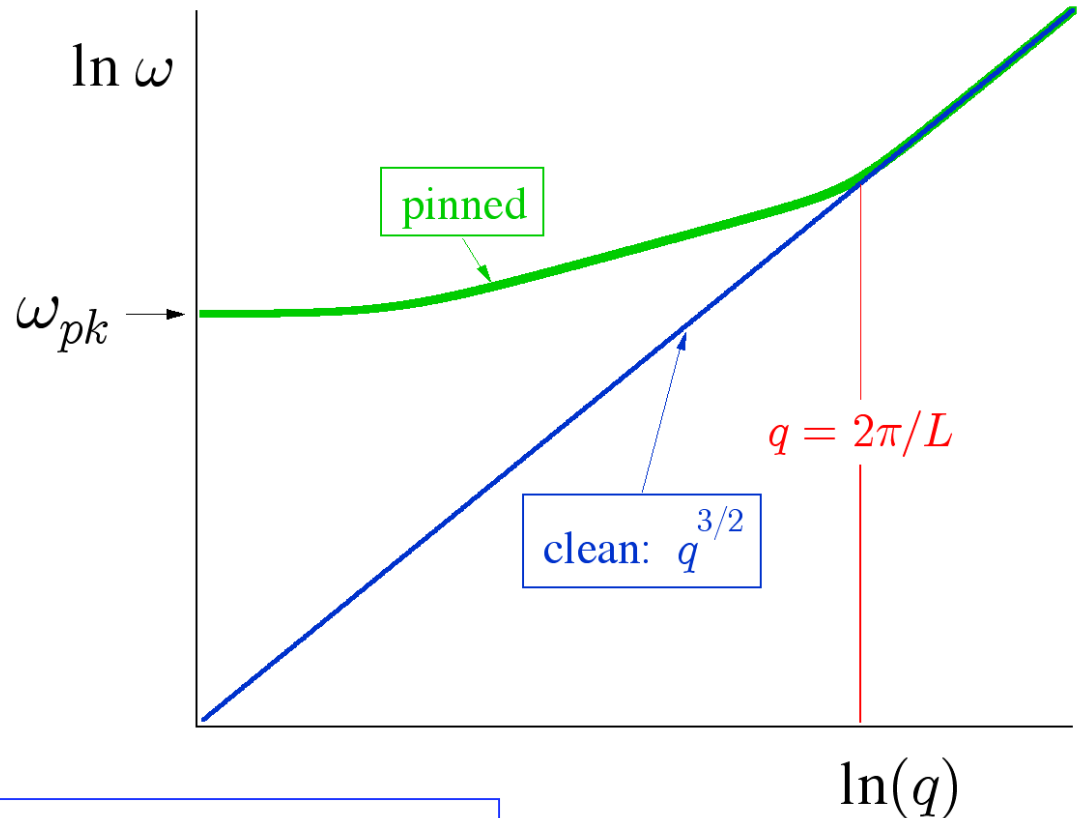
# Resonance: pinning mode interpretation

*Disorder* induces “Pinning” Mode: small oscillation about pinned positions

Disorder

$$\Rightarrow L$$

$$\Rightarrow \omega_{pk} \sim \omega(q \sim 2\pi/L)$$



Classical Wigner crystal in high B:

**Without disorder:**  $\omega \sim q^{3/2} B$

**With disorder:** saturates at low  $q \sim 2\pi/L$

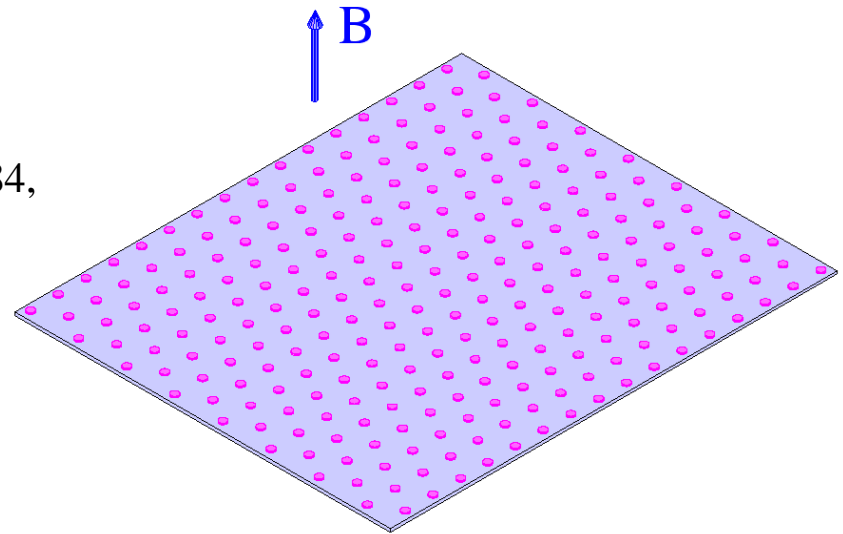
# Wigner solids in QHE systems

Predicted low- $\nu$  state:

Lam and Girvin; Levesque, Weis, MacDonald '84,

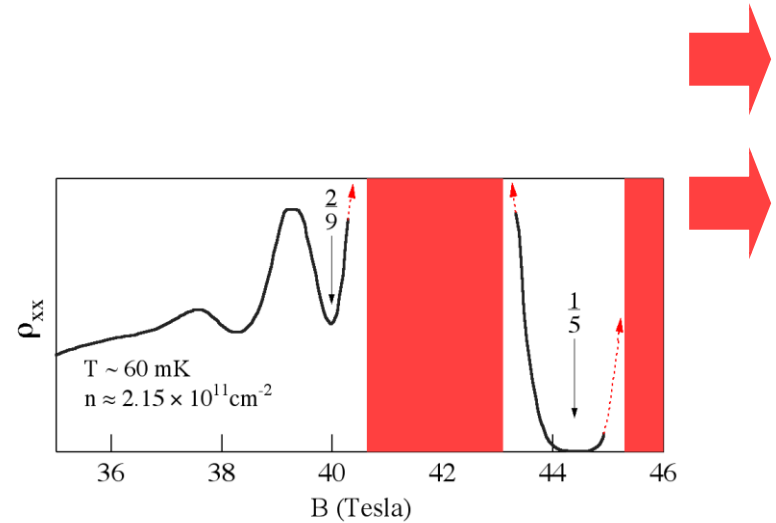
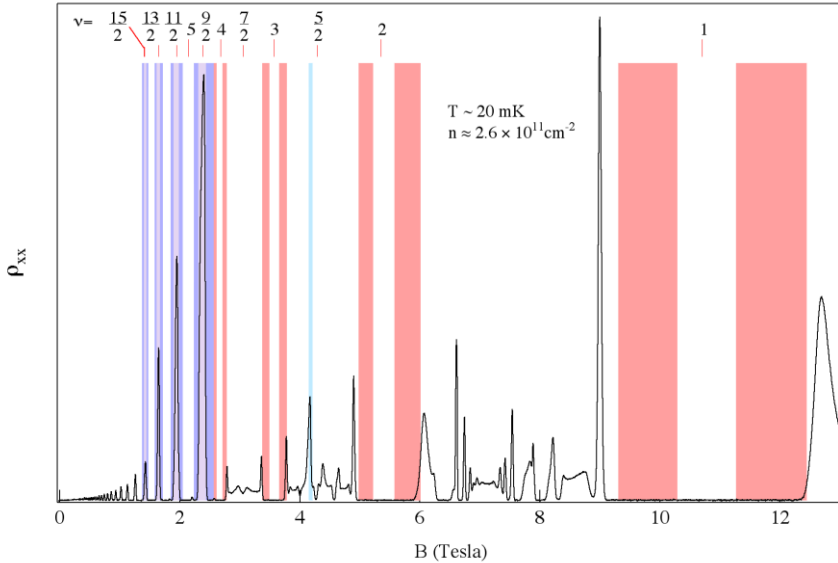
Lozovik and Yudson '75,

Yang and Rezayi, '02



- **Spatial charge distribution** effect on NMR lineshape:  
L. Tiemann, T. D. Rhone, N. Shibata, and K. Muraki,  
Nat. Phys. '14.
- **Tunneling approach** (Ashoori, arxiv)
- **Composite Fermion Wigner crystal**  
Archer, Park, Jain, PRL '13 ; Rhim, Jain, Park, PRB '15

# Resonance: pinning mode of electron solid, $\nu$ ranges of resonances



Integer Quantum Hall Effect Wigner Crystal

High B Wigner Crystal

Bubble phase

Stripe phase (anisotropic)

N=1 Landau level bubble phase

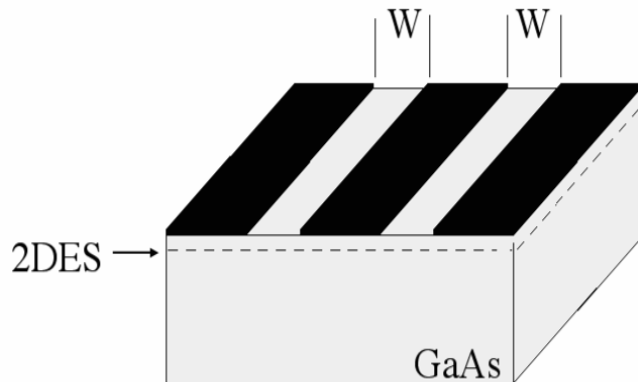
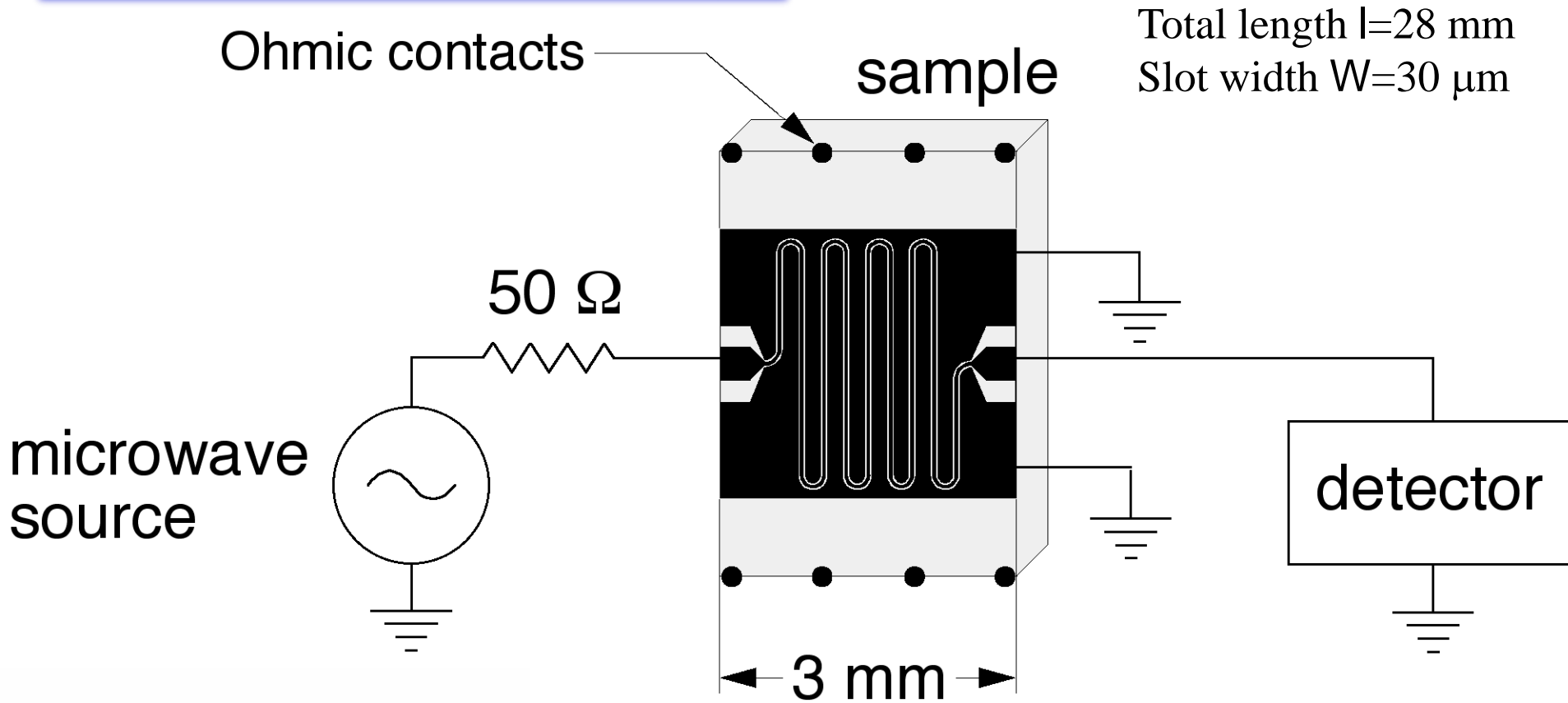
2010: within 1/3 FQHE

*“solid” phases found in many conditions.*

Resonance depends on disorder and solid stiffness:

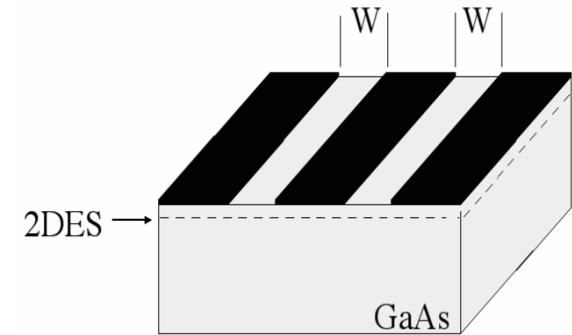
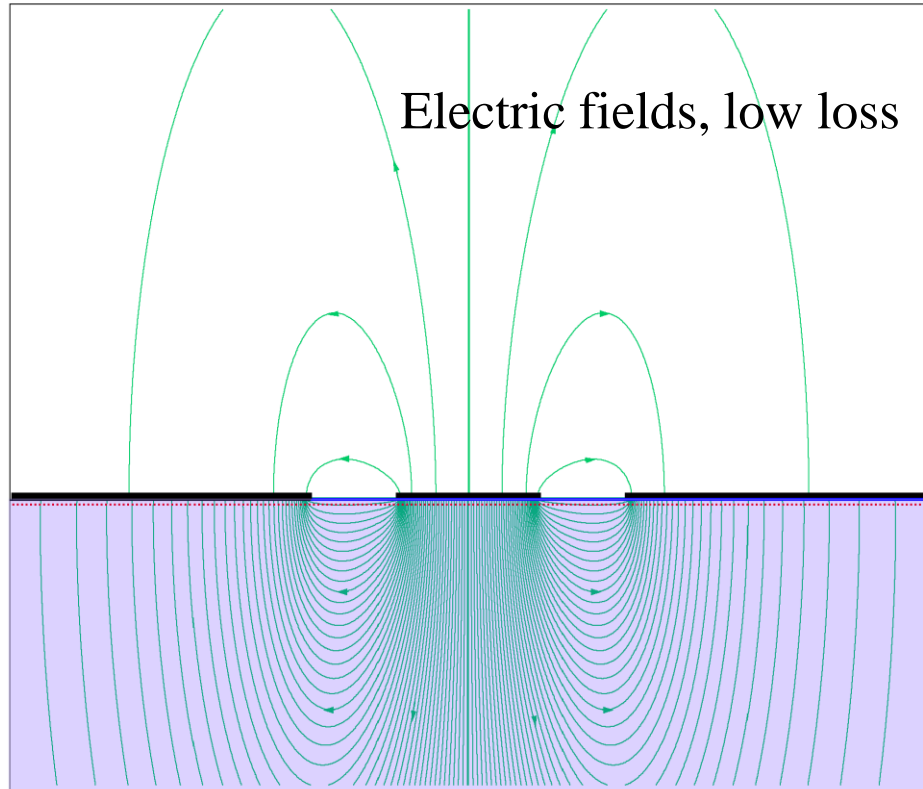
**phase transitions, to/ between solids** at  $\nu$ , T where dc just shows QHE or IP

# Microwave measuring technique



- Metal film makes coplanar waveguide (CPW) transmission line
- Center conductor driven, side planes grounded “like coax”
- $\sigma_{xx}$  from 2DES effect on signal

# Microwave measurement, coupling to 2DES



CPW metal film

2DES

- Relevant 2DES is under the slots
- CPW - 2DES coupling is capacitive

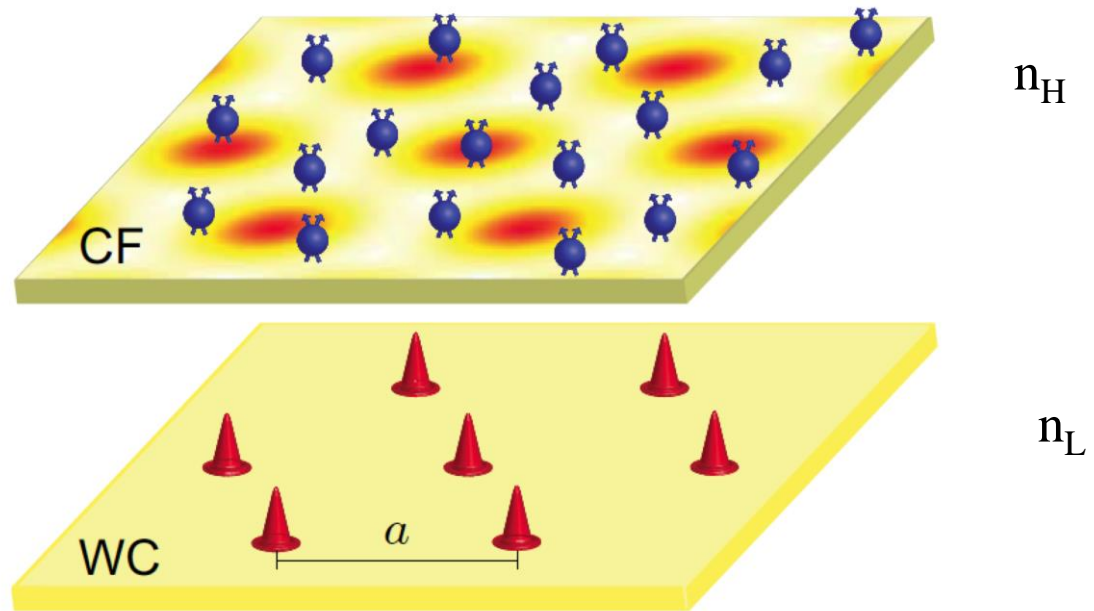
- **f-independent extinction**  $P = \exp(-Z_0 \text{Re}(\sigma_{xx}) N_{sq})$
- $Z_0$  characteristic impedance for  $\sigma_{xx} = 0$ ,  $N_{sq} = 2l/W$ ,  $l$  is line length
- Formula is for high  $f$ , low loss limit.

## Outline

- Double quantum well CF liquid+ WS
- Multiple Wigner solid phases in bilayer-regime wide QW



# Wigner Solid + Composite Fermion Liquid



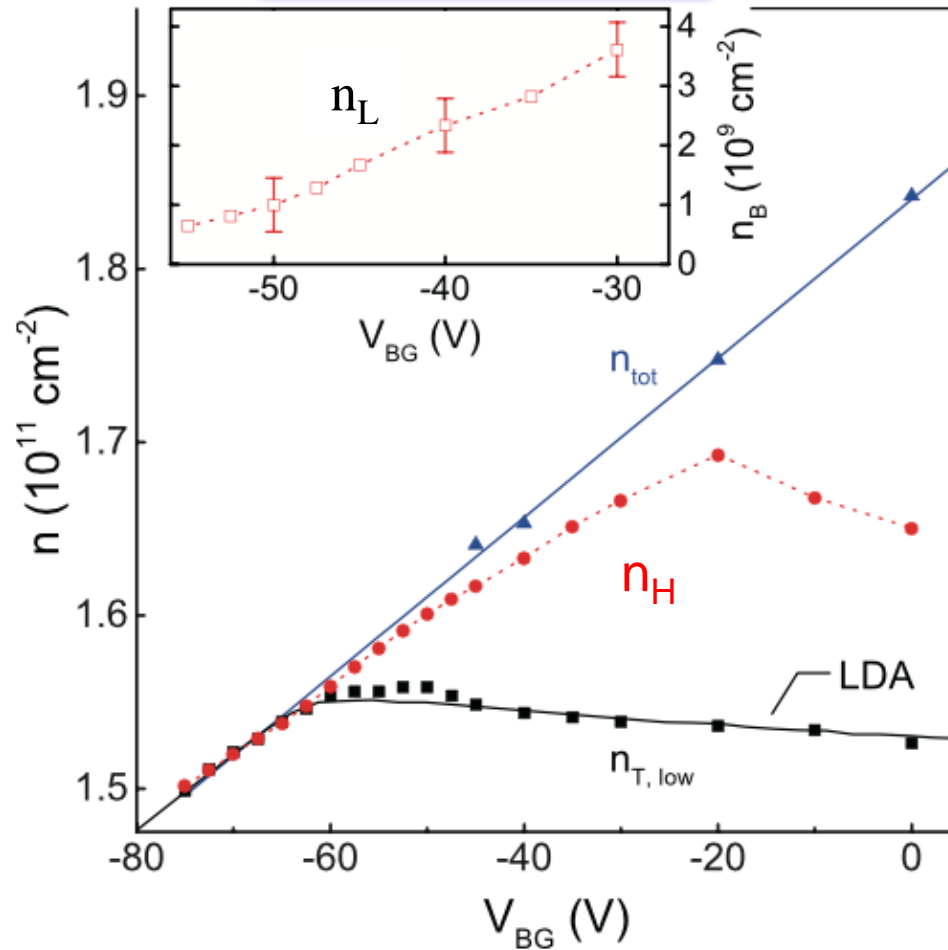
Double quantum well: 10 nm barrier, 30 nm wells

Highly unbalanced layer densities:  $n_H \sim 1.5 \times 10^{11}$ ,  $n_L \sim 2 \times 10^{10} \text{ cm}^{-2}$

Bottom (minority) layer: WS, top (majority) layer: FQHE regime.

Original purpose ( Shayegan group): geometric resonances of CFs  
arxiv 1410.3435 (Deng,Liu,Jo,Pfeiffer,West, Baldwin,Shayegan)

## Determining $n_L$

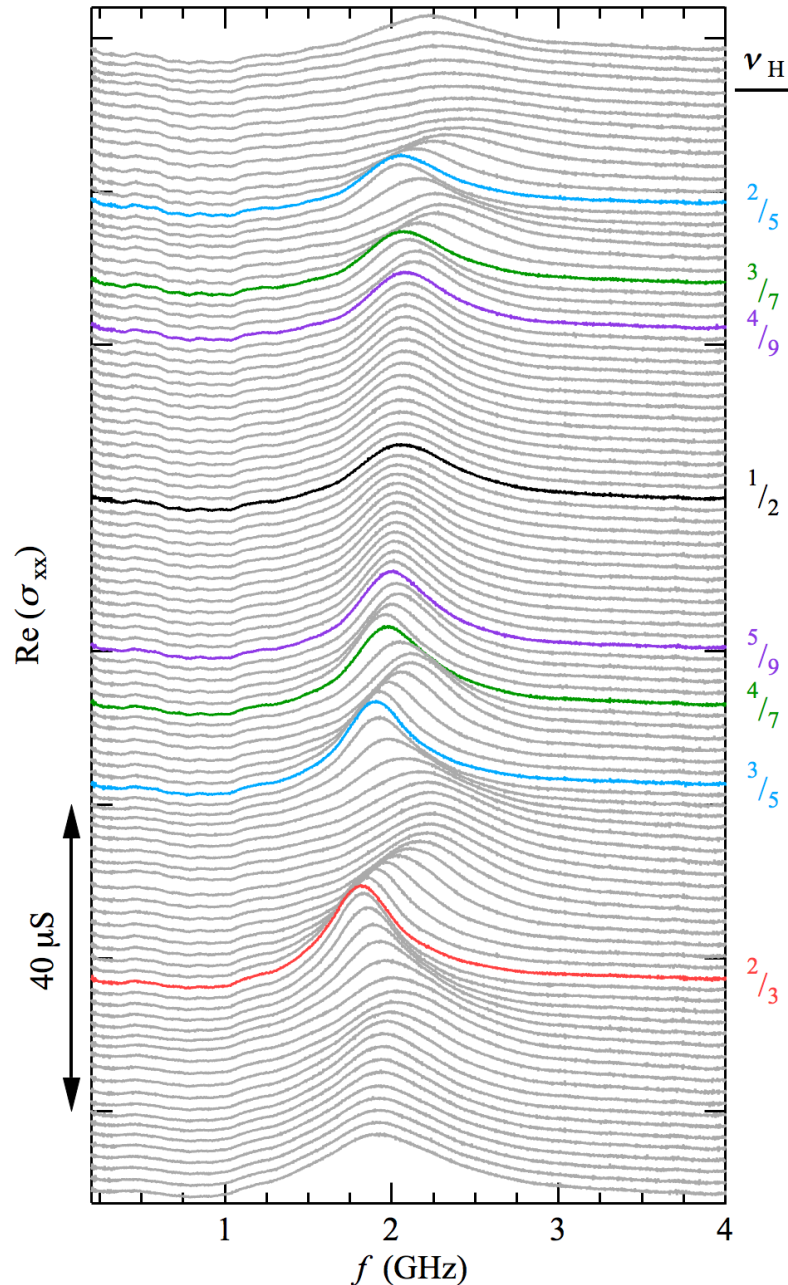


$$n_L = n_{tot} - n_H$$

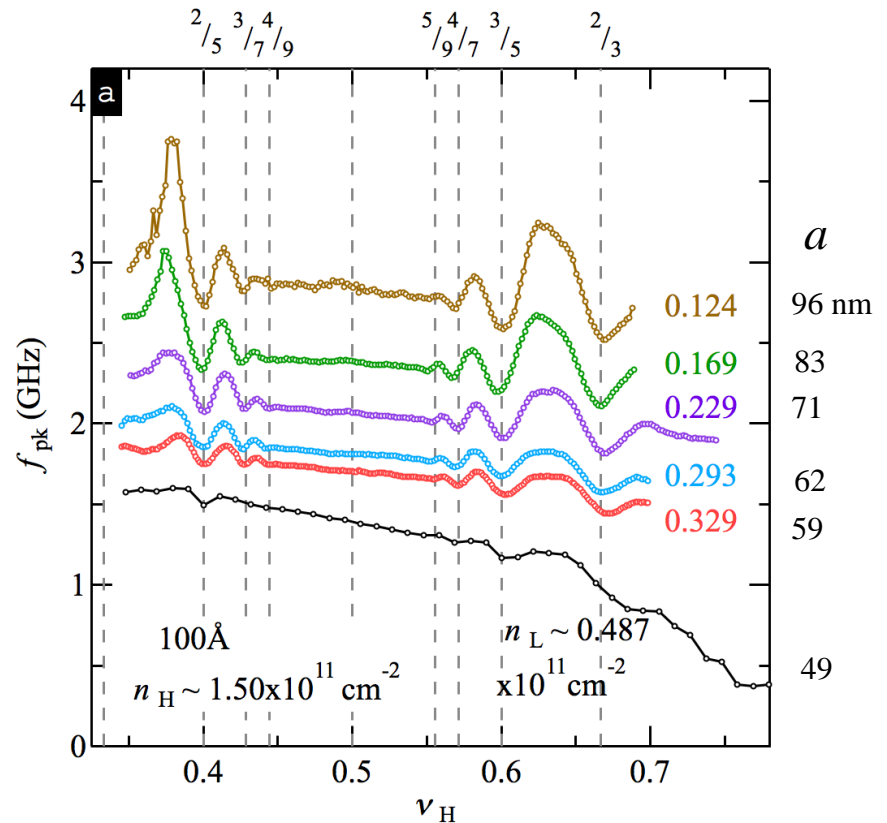
- Charge transfer for  $\nu\sigma l$ ; gone for lower  $\nu$ .
- $n_L$  by subtraction of  $n_L$  (by FQHE) from SdH total density
- arxiv 1410.3435 (Deng,Liu,Jo, Pfeiffer,West, Baldwin,Shayegan)

# Minority layer pinning mode spectra

$$n_H = 15.0; n_L = 2.29 \times 10^{10} \text{ cm}^{-2}$$

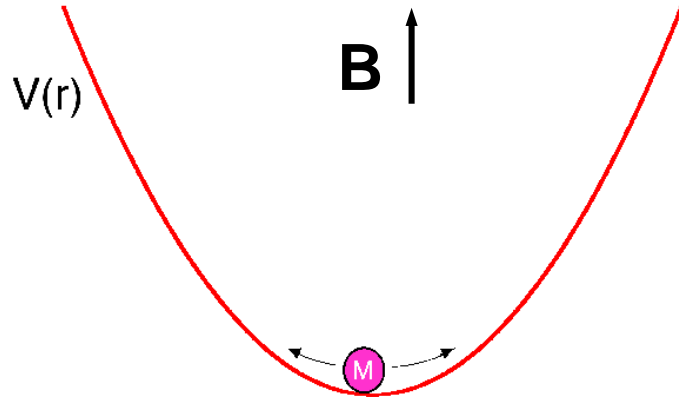


Top layer does *not* shield from MWs



$f_{pk}$  responds to FQHE in majority layer  
 Interlayer coupling, small enough  $n_L$  :  
 Lattice constant  $a$  exceeding  
 separation  $d \approx 40 \text{ nm}$

# Sum rule: Harmonic oscillator model of pinning mode



$$V(x, y) = \frac{M\omega_0^2(x^2 + y^2)}{2}$$

“pinning” frequency  $\omega_0$ ,  
cyclotron frequency  $\omega_c = eB/m^*$

Charge in “pinning” potential

Two modes:

$$\omega_+ \geq \omega_c$$

$$\omega_- = \omega_0^2 / \omega_c \quad (\text{for } \omega_0 \ll \omega_c)$$



Microwave resonance

Observed resonance frequency:  $f_{pk} = \omega_0^2 / 2\pi\omega_c$

$$\omega_- \text{ sum rule: } S_- = \int_0^\infty \text{Re}[\sigma_{xx}(f)]df = n_{osc} e \pi f_{pk} / 2B$$

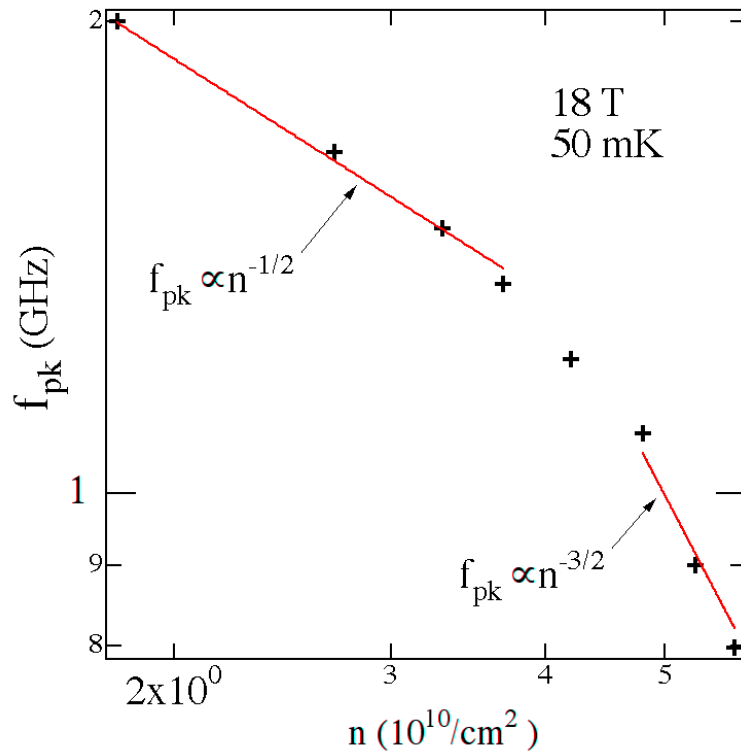
from measured  $S/f_{pk}$ , participating carrier density:  $n_{osc} = 2BS_- / e \pi f_{pk}$

Participation ratio

$$/ = n_{osc} / n$$

Fukuyama and Lee;  
Millis, Normand, Littlewood

## $f_{pk}$ increases as $n$ decreases: Weak pinning



Generic behavior

Reducing  $n \Rightarrow$  weaker carrier-carrier interaction  
 $\Rightarrow$  Carriers “fall further into impurity potential”  
 $\Rightarrow$  Average pinning, so  $f_{pk}$  increases

■ In weak pinning:  $f_{pk} \sim 1/C_t$  inversely as shear modulus.

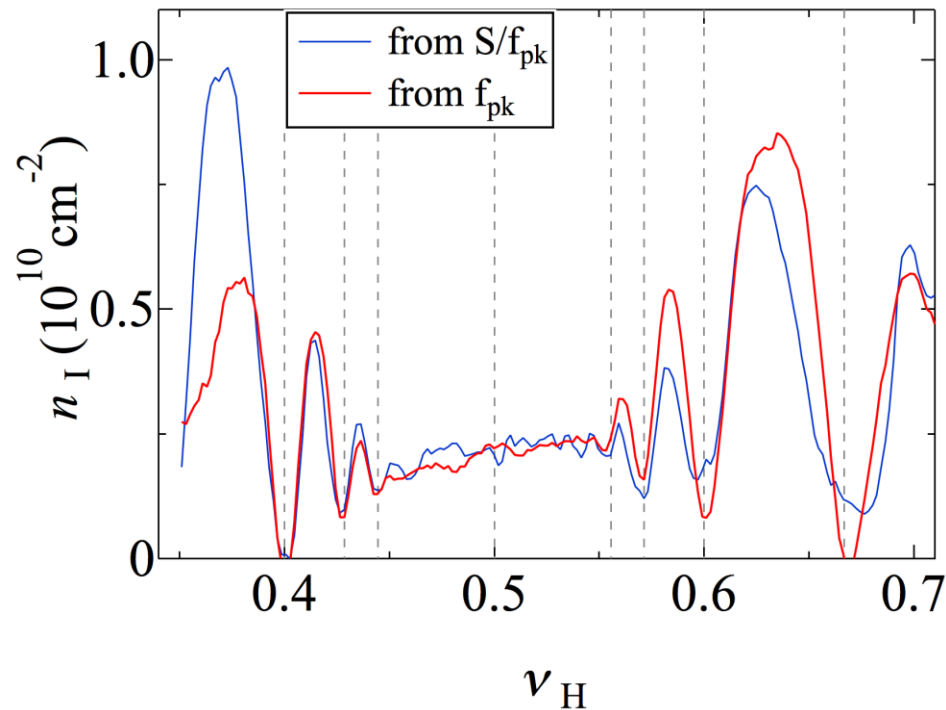
## $n_{osc}$ characterizes effect of majority-layer state: image charge

Two ways to get participating density  $n_{osc}$  from resonance :

- i.  $n_{osc} \propto f_{pk}^{-2}$  : empirically established
- ii.  $n_{osc} = 2BS/e\pi f_{pk}$  : sum rule for  $n$ ,  $S$  is integrated  $\text{Re } \sigma_{xx}(f)$

$$n_I = n_L - n_{osc}$$

$$n_L = 2.29 \times 10^{10} \text{ cm}^{-2}$$



$n_I$  : “image charge” density, reduction in resonance-measured density from true density,  $n_L$

- local compressibility measurement

## Two independent ways to get $n_I$

In pinning theory (Chitra et al 2001, Fertig 2000, Fogler 2001)

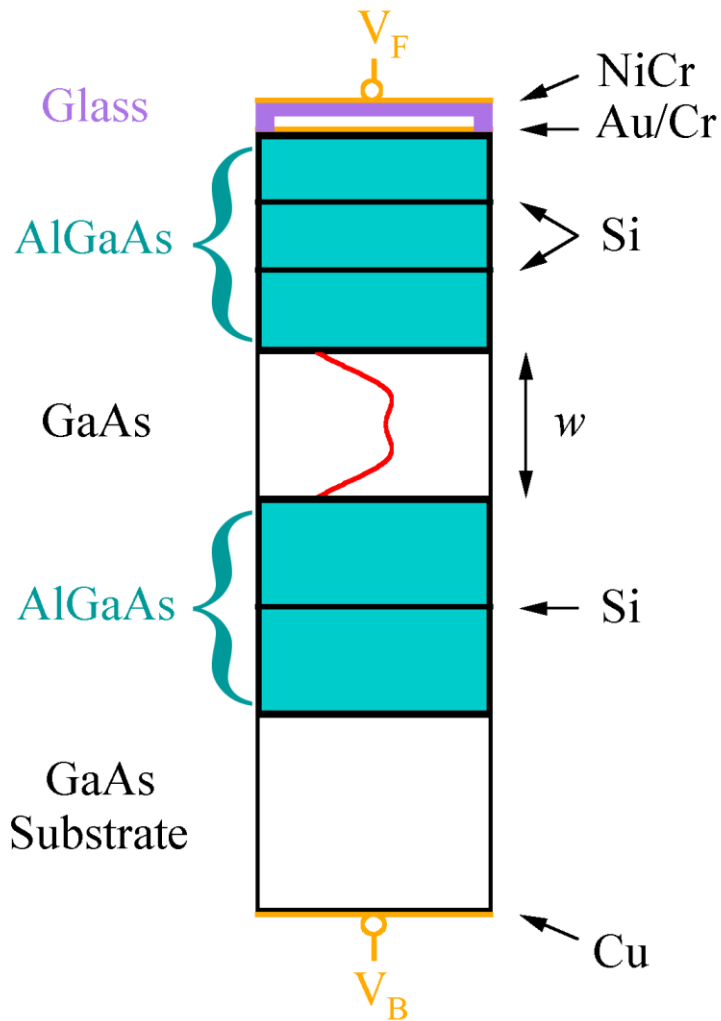
$f_{pk}$  comes from static quantity

Larkin length + Lorenz force + shear modulus

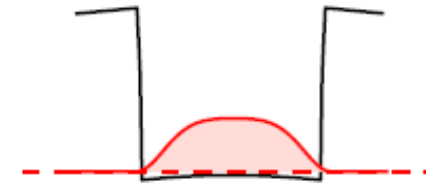
Sum rule measures all oscillating charge

“image” charge in majority layer appears to oscillate along with WS charges.

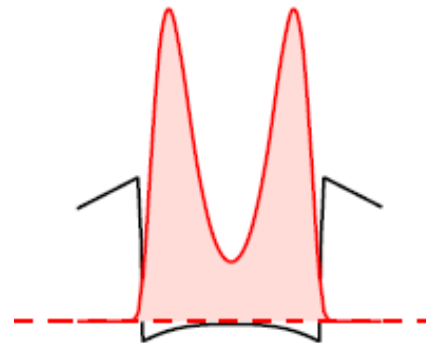
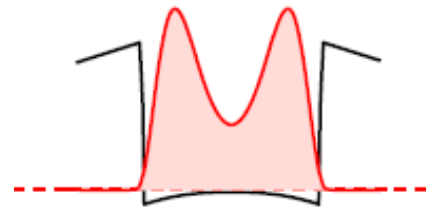
# Wide quantum well



Increasing density,  $n$



Low  $n$ , narrower  
Single layer

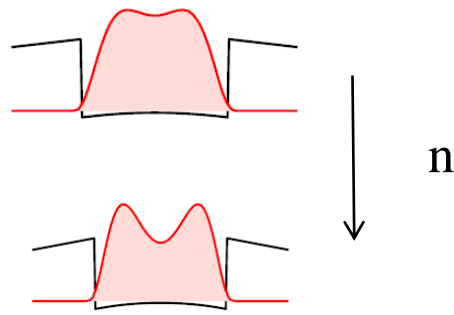


High  $n$ , wider  
increased tendency  
to form bilayer states

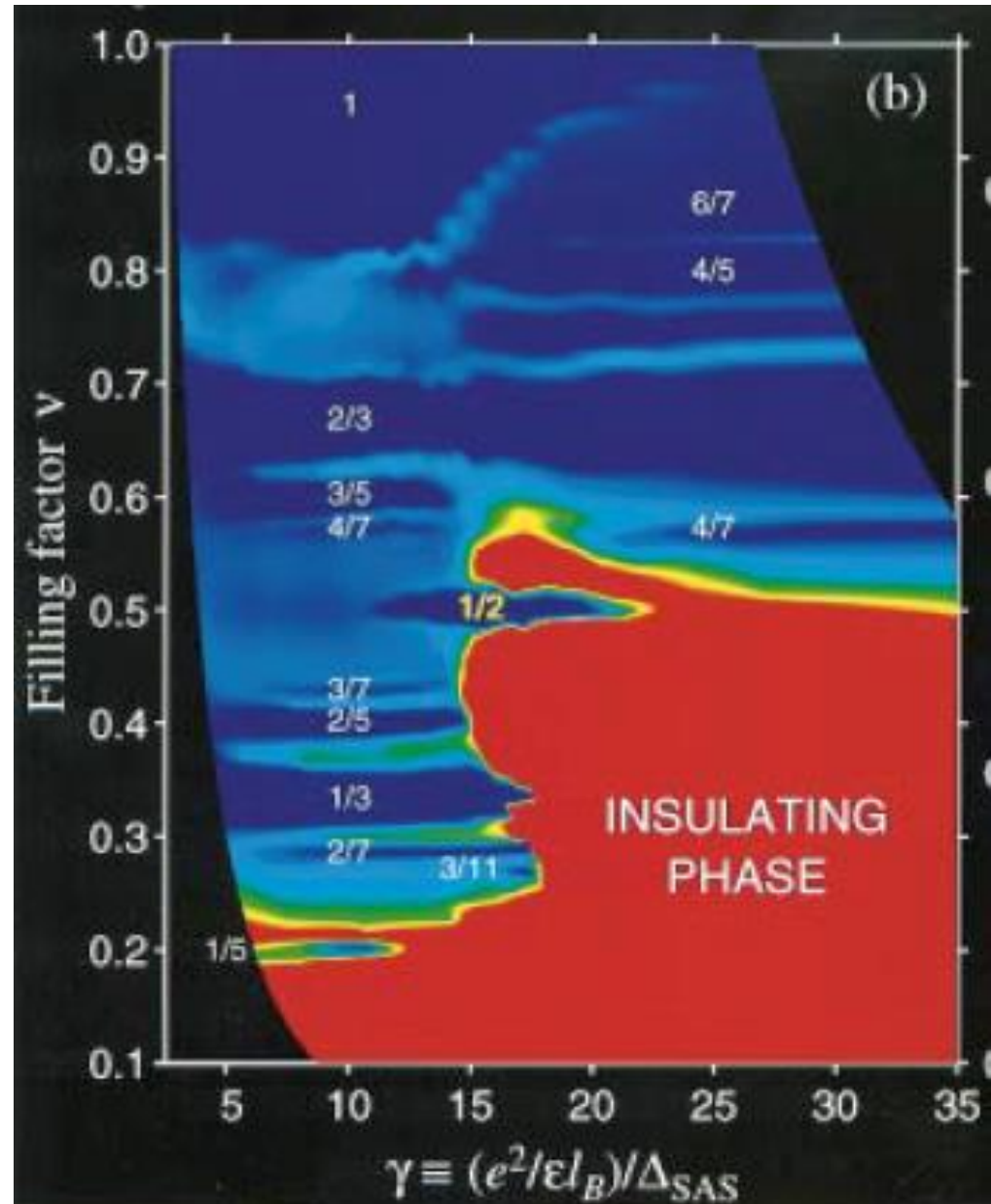
Air-gapped glass top gate: necessary for microwaves



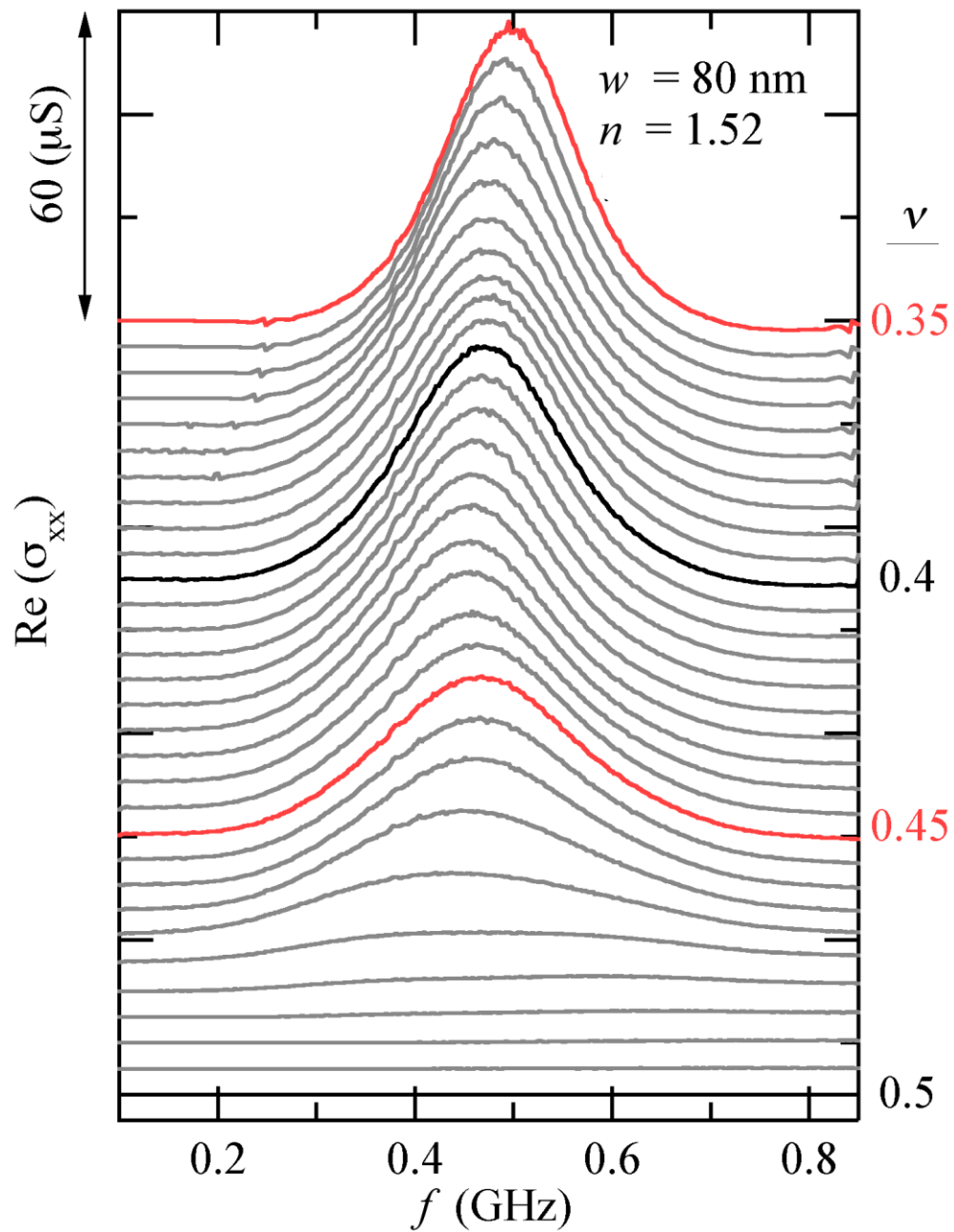
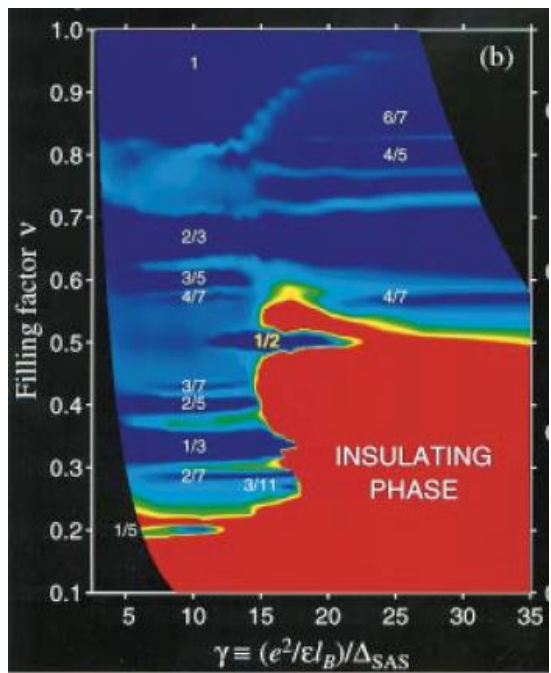
# Wide quantum wells WQW



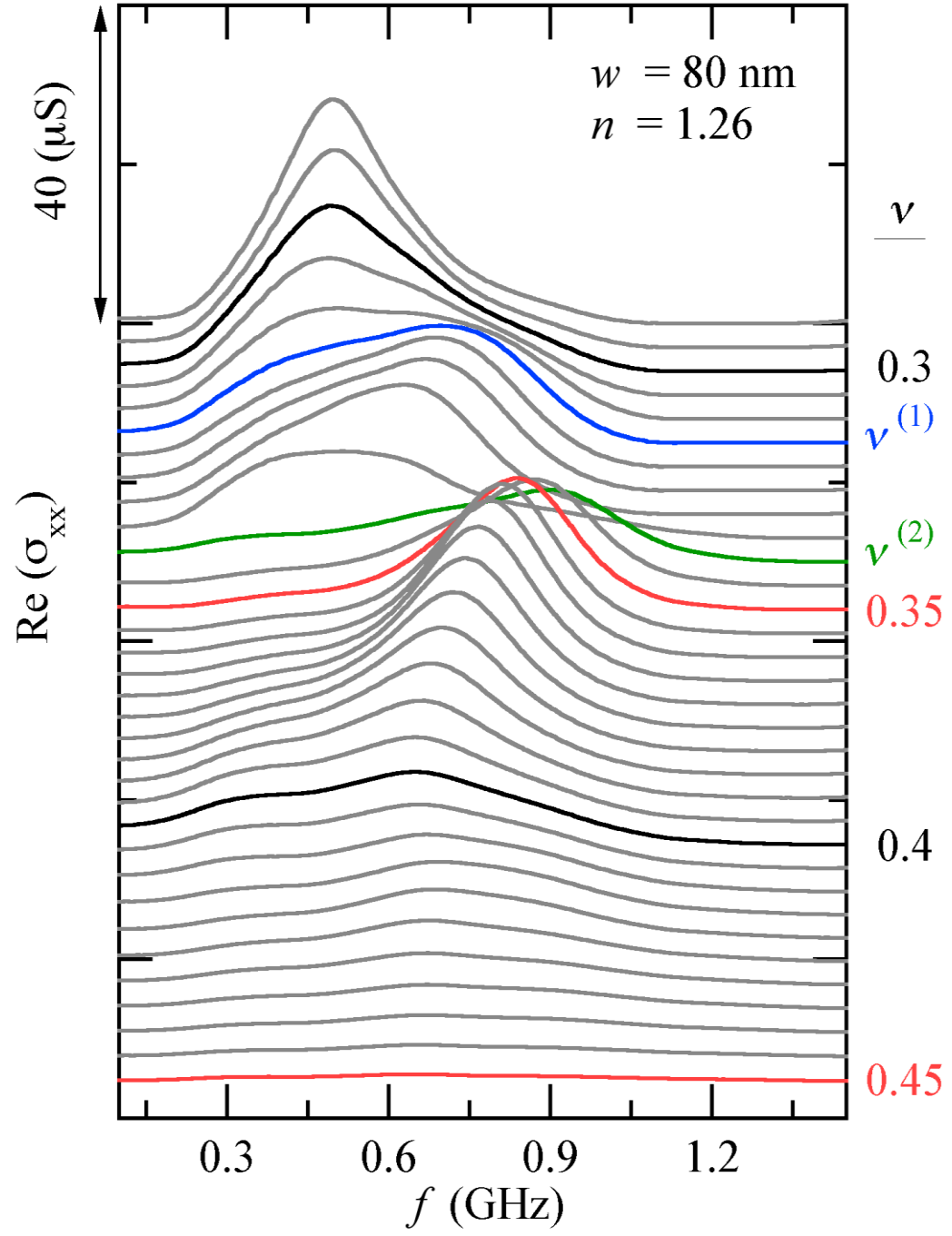
- two-component for  $\gamma = E_c / \Delta = e^2 / 4\pi\epsilon_0\epsilon l_B \Delta > \sim 16$   
 $\gamma$ : measure of *bilayerness*
- transition to solid
  - single layer :  $\nu \sim 1/5$
  - parallel single layers  $\nu \sim 2/5$  (1/5 per layer)
- Interlayer correlated:
  - eg  $1/2$  FQHE



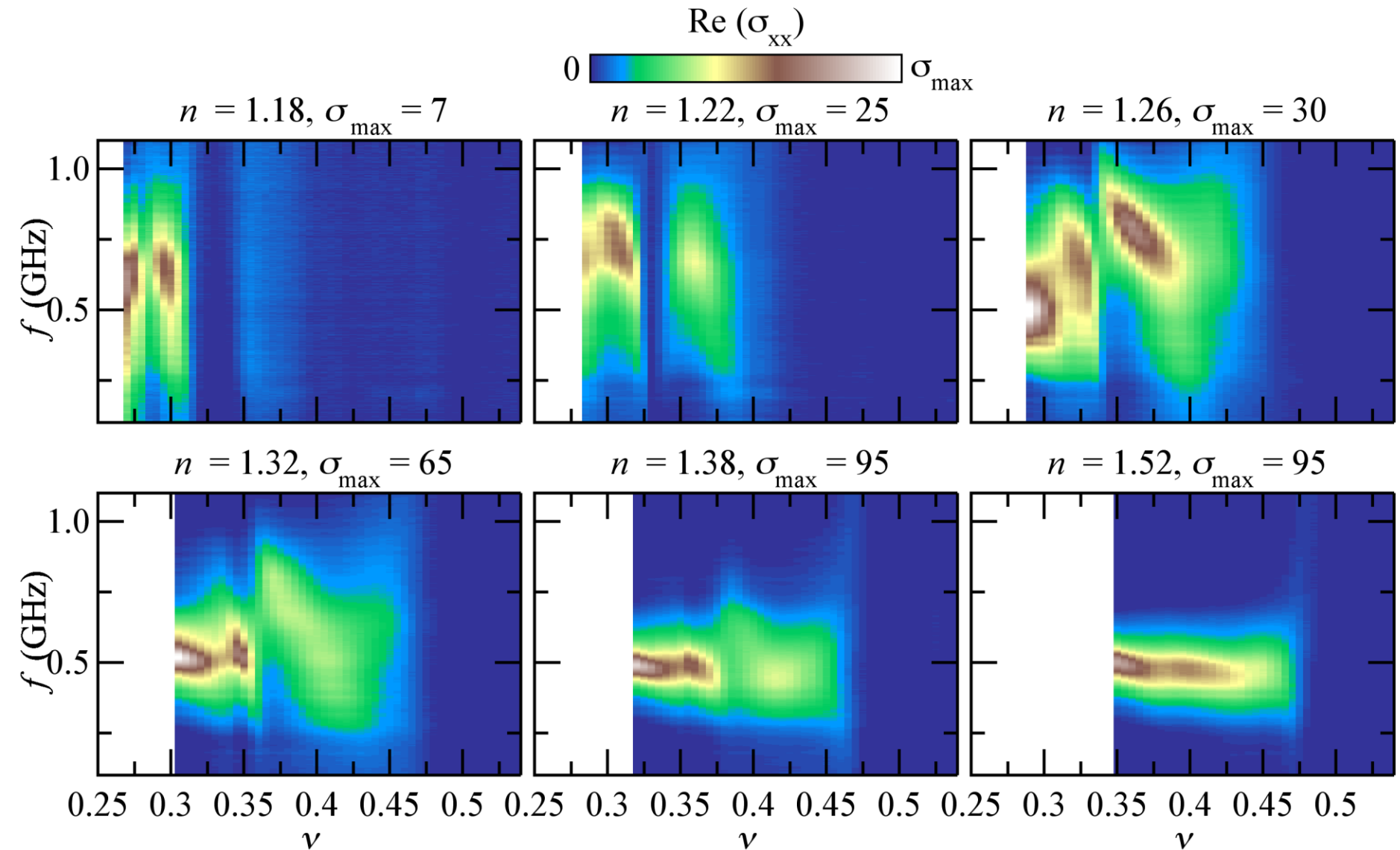
# Resonance onset



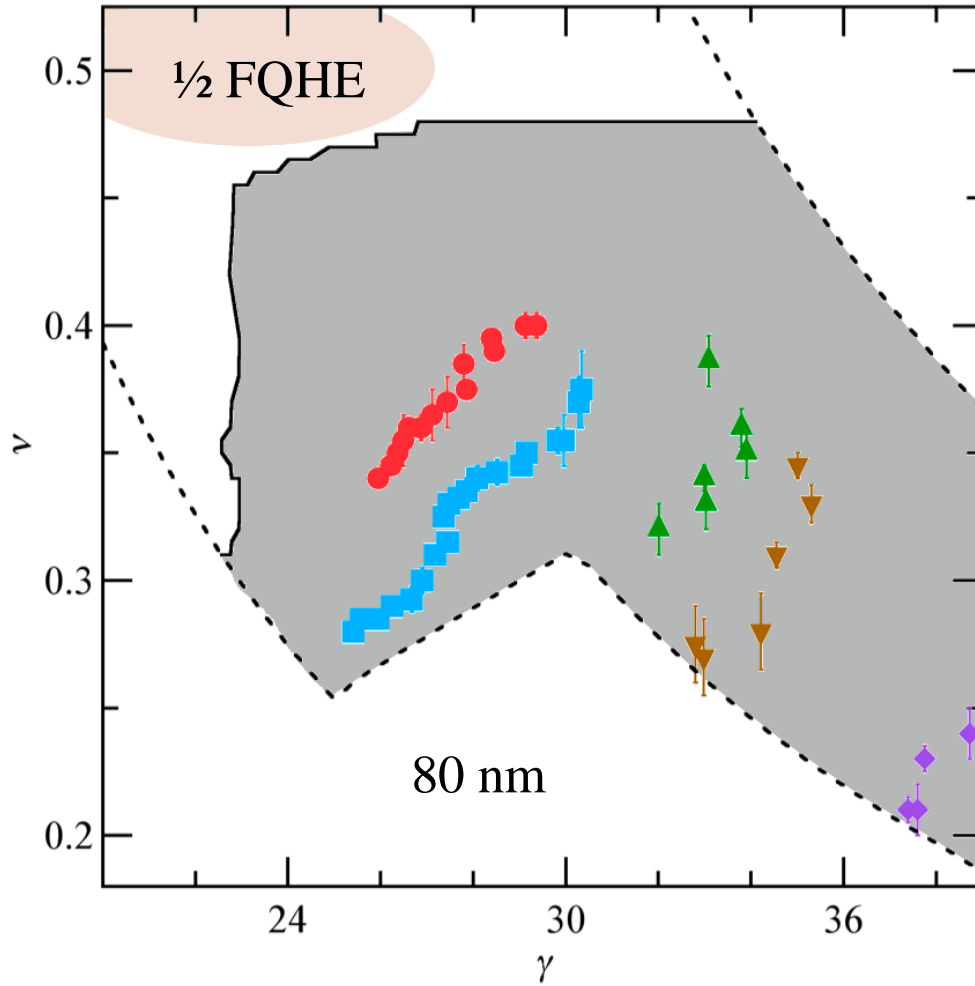
# Phase transitions



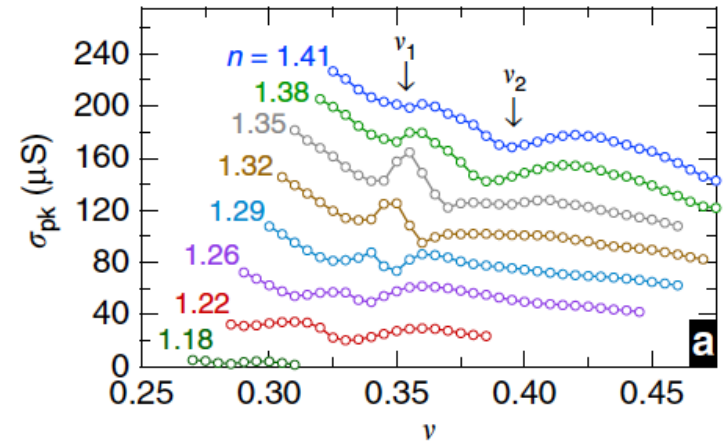
# Microwave Spectra ( $w = 80$ nm)



# five phase transitions in terminating insulator

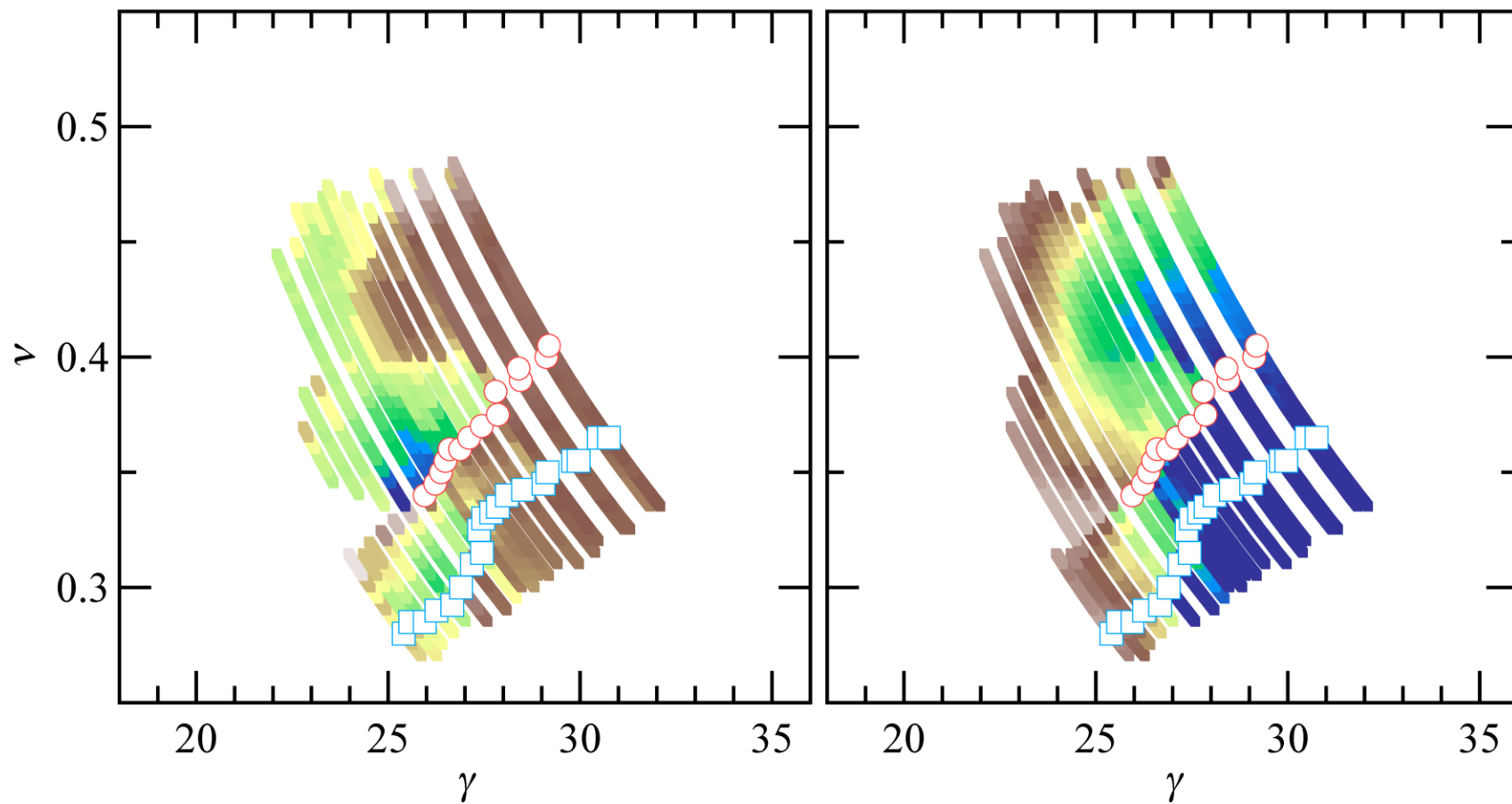
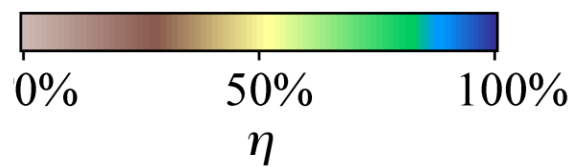
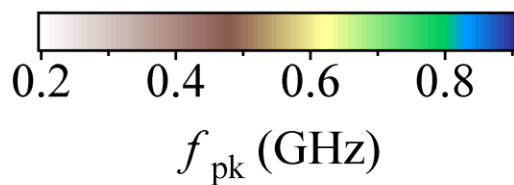


$$\nu = nh/eB, \quad \gamma = E_c/\Delta_{SAS}$$



dashed lines: experimental limits

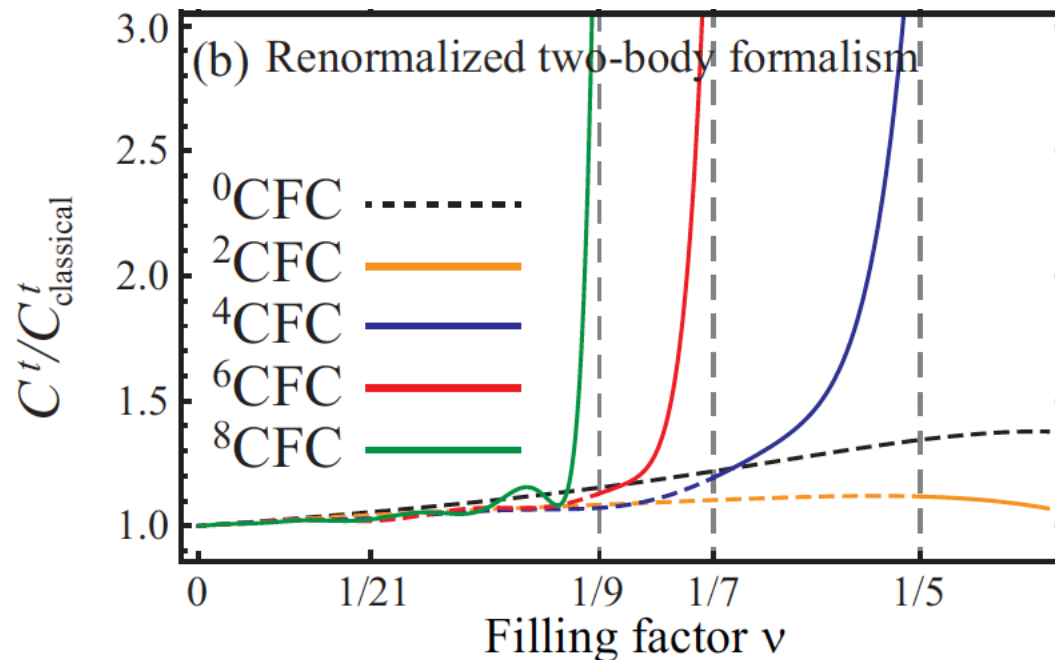
# Phase Diagram (80 nm)



$$\nu = nh/eB, \quad \gamma = E_c/\Delta_{SAS}, \quad \eta = \% \text{ participation}$$

## Possible explanations

- CFWC: Composite Fermion flux number ( $2p$ ) transitions  
Archer, Park, Jain, PRL '13 ; Rhim, Jain, Park, PRB '15  
 $p \rightarrow 2,3,4$ , as  $\nu$  goes below  $\sim 1/5, 1/7, 1/9$
- Single layer no disorder
- Shear modulus has discontinuity at transitions

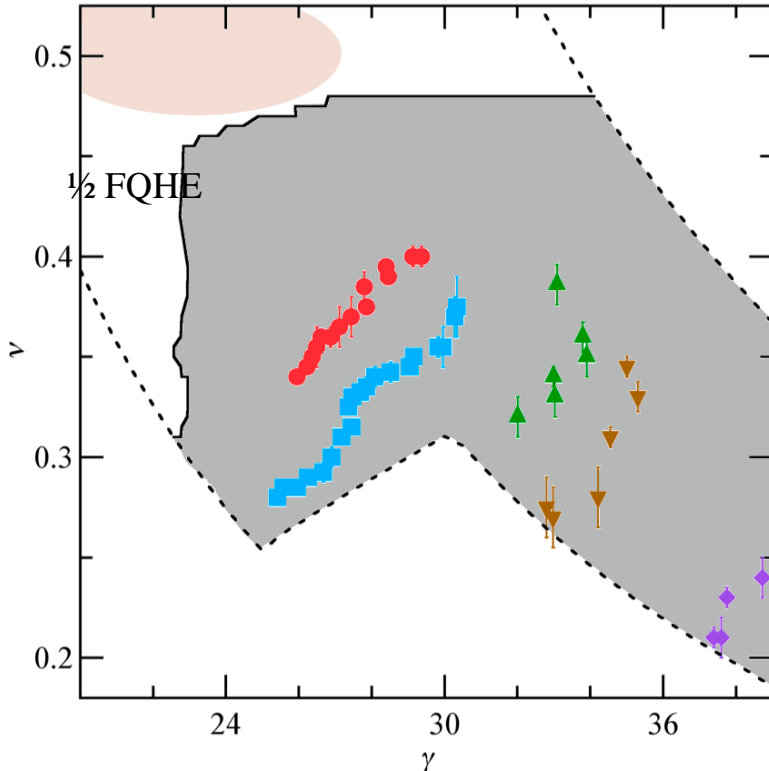
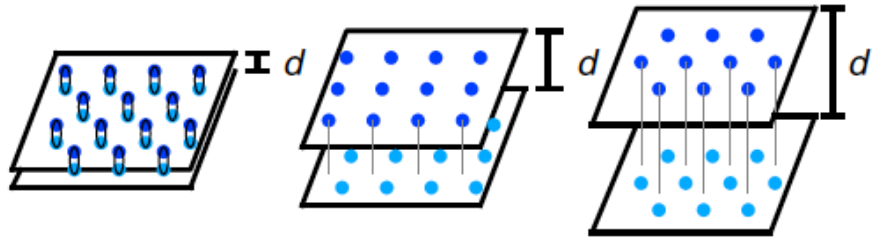


# Possible explanations

- Bilayer structural

HF theory : Narasihhan Ho, '95 ,

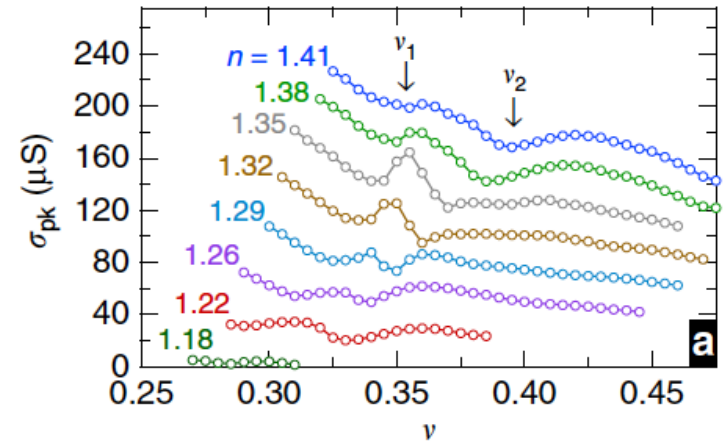
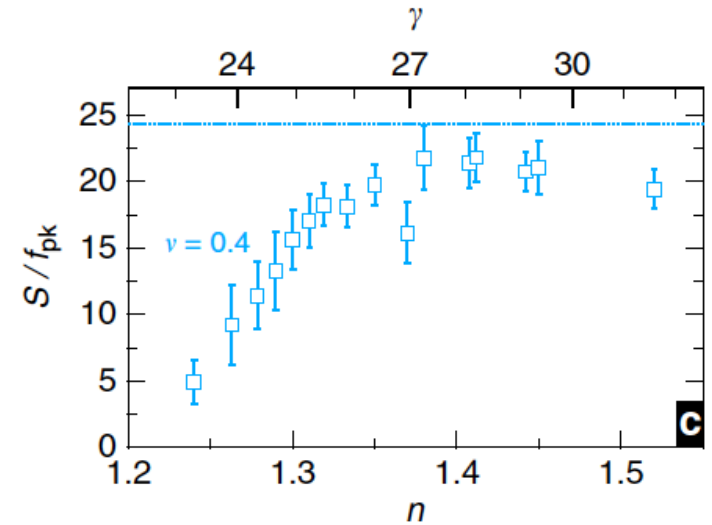
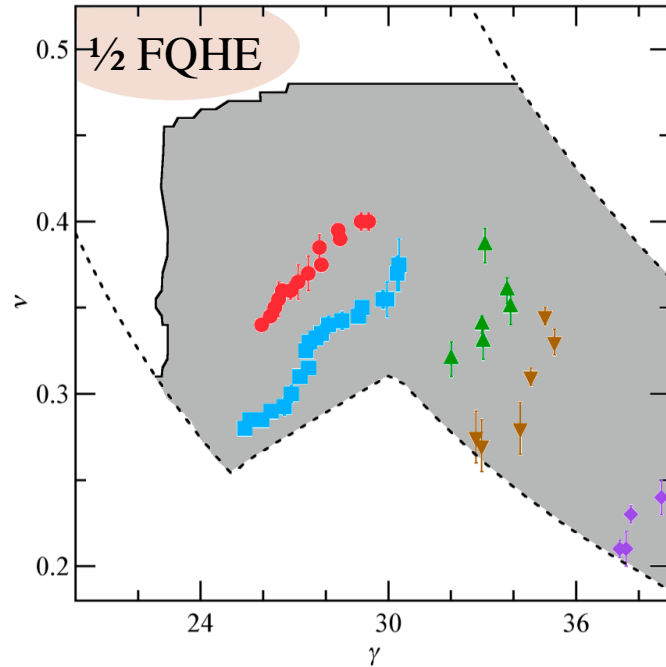
Cote, Fertig, '95



Wrong trajectory

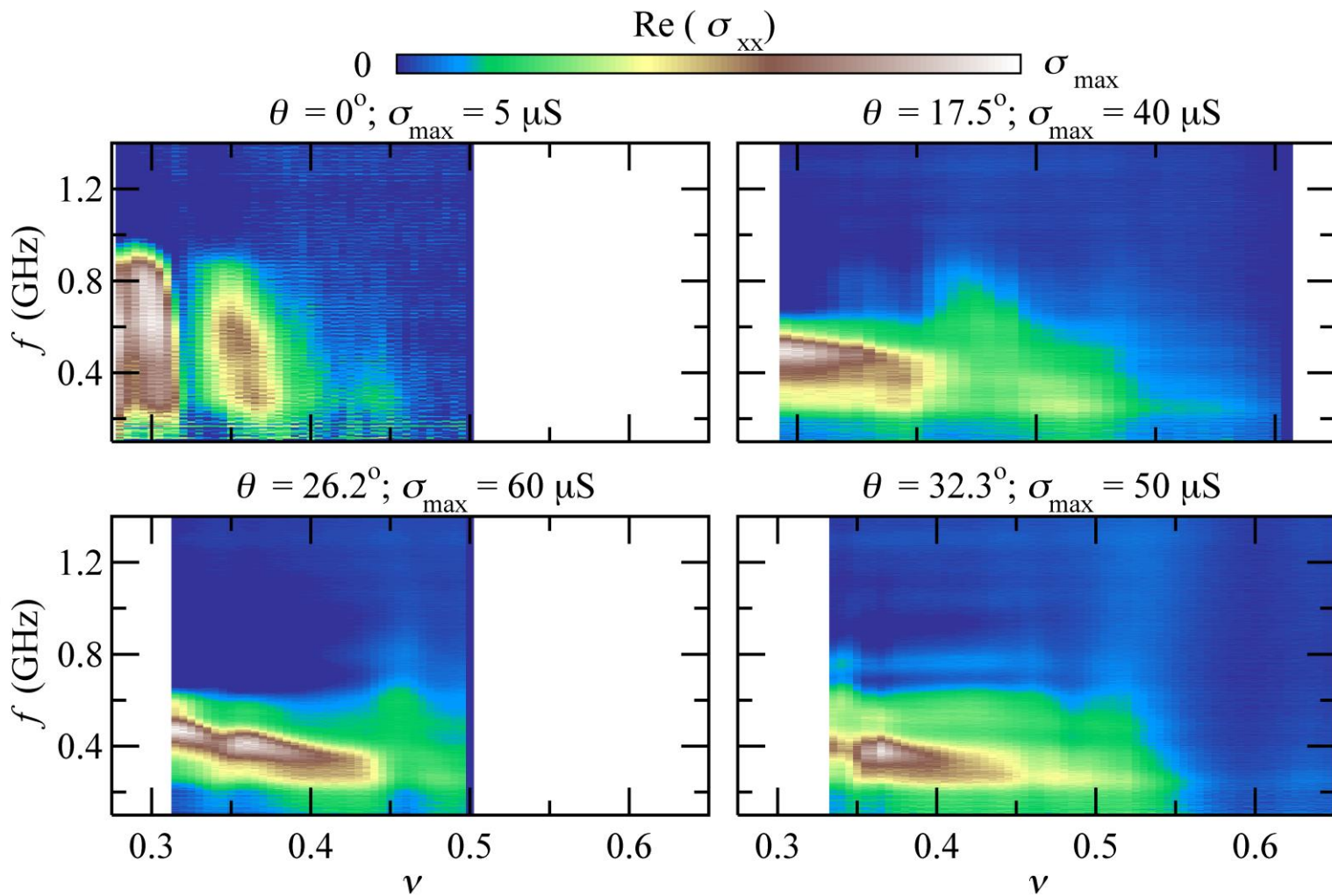
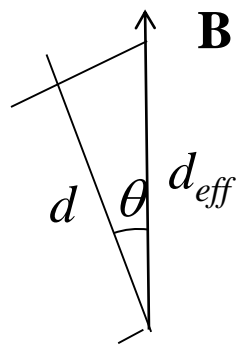


# Admixture/microemulsion



- Resonance turns on gradually as  $\gamma$  increases
- Transitions most pronounced at moderate  $\gamma$
- Role of liquid or other nonresonant component
- Admixture/microemulsion, (Kivelson, Spivak)

# Tilt sample in field: Microwave Spectra ( $w = 80$ nm)

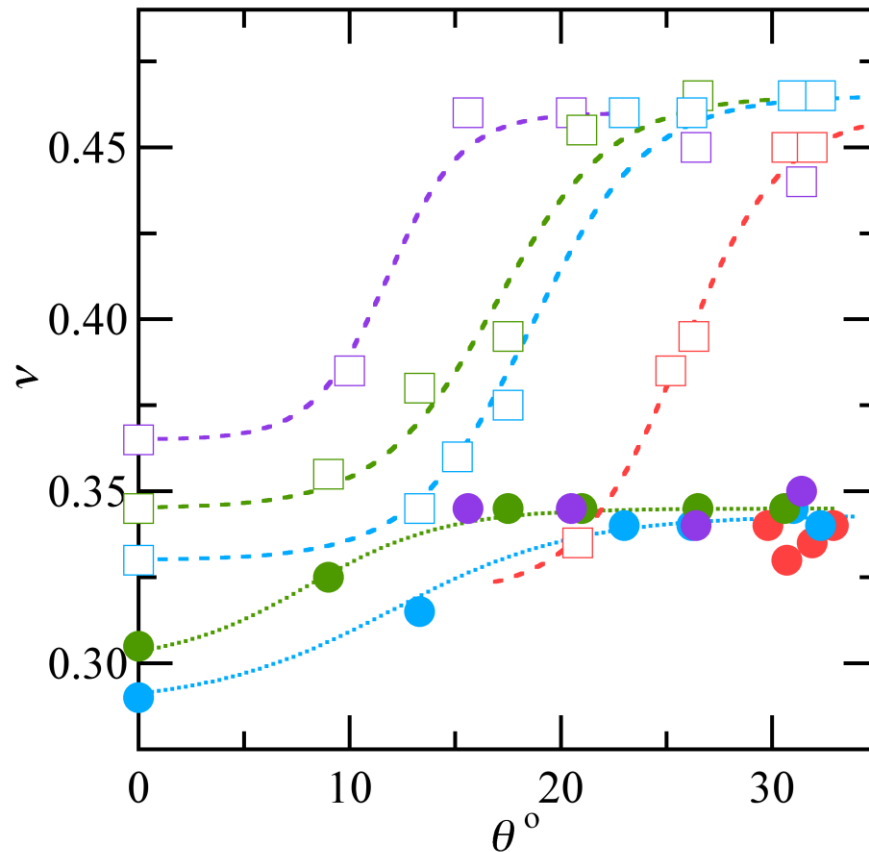


$$n=1.21$$

In-plane B increases sharpness, hence peak  $\text{Re} \sigma_{xx}$ .

## Transition movement (80 nm)

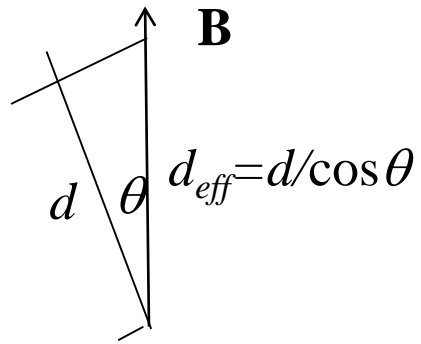
●  $n = 1.11$ ; ●  $n = 1.21$ ; ●  $n = 1.27$ ; ●  $n = 1.33$



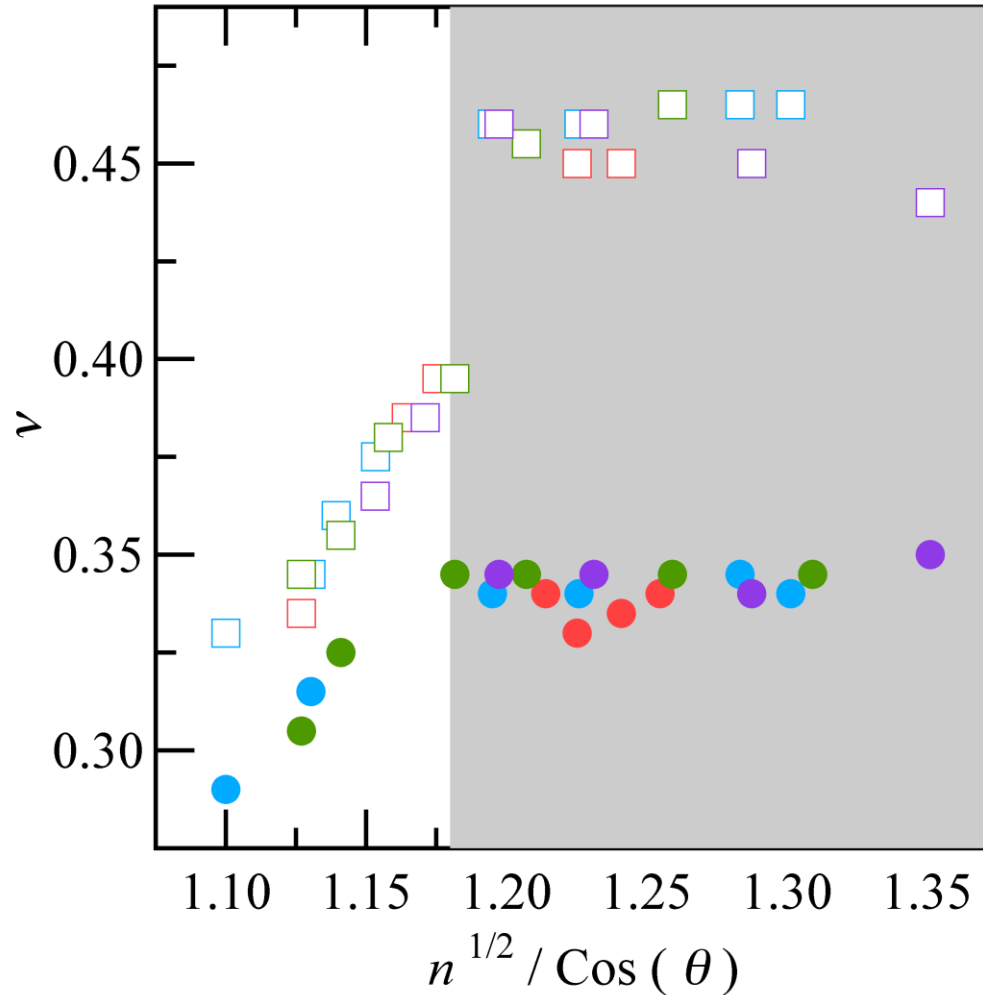
Increasing  $n$  or  $\theta$  (bilayeriness):

- Phase transition position moves to higher  $\nu$
- Reduction in tunneling
- Not consistent with HF predictions

## Data collapse (80 nm)



$$n^{1/2} / \cos \theta \sim d_{eff} / a$$



Two regimes:

- Low  $\theta$ : modification of  $\Delta_{SAS}$
- High  $\theta$ :  $n$  and  $\theta$  independent transitions--- $\nu$  determined

- DQW: CF liquid + WS

$$\nu_H \text{ (} \mathcal{R}n_I \text{)}$$

- Resonance associated with a bilayer electron solid in a wide quantum well
  - Deep in the insulating state: *five* phase transitions

*Possibilities...*

  - CF vortex number transitions
  - Liquid/solid emulsion
  - Bilayer stacking transitions
  - $\nu$  characterizes transitions at high in-plane field

Hatke, Liu, Engel, Shayegan, Pfeiffer, West, Baldwin, Nature Comm. **6**, 7071 (2015)

Hatke, Liu, Engel, Shayegan, Pfeiffer, West, Baldwin, arXiv: 1504.08182